





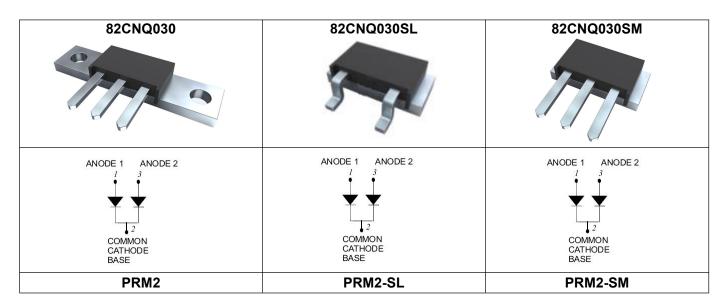
## 82CNQ030 SCHOTTKY RECTIFIER

#### **Applications**

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

#### **Features**

- 150°C T<sub>J</sub> operation
- Center tap module
- Very Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- · Low profile, high current package
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional electrical and life testing can be performed upon request



#### **Maximum Ratings:**

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	$egin{array}{c} V_{RRM} \ V_{RWM} \ \end{array}$	-	30	V
Average Rectified Forward Current	I <sub>F (AV)</sub>	50% duty cycle @T <sub>C</sub> =119°C, rectangular wave form	40(Per Leg) 80(Per Device)	Α
Peak One Cycle Non-Repetitive Surge Current(Per leg)	I <sub>FSM</sub>	8.3 ms, half Sine pulse, T <sub>J</sub> = 25 °C	1060	Α
Non-Repetitive Avalanche Energy (Peg leg)	Eas	T <sub>J</sub> =25℃,I <sub>AS</sub> =8A,L=1.12mH	36	mJ
Repetitive Avalanche Current(Peg leg)	I <sub>AR</sub>	Current decaying linearly to zero in 1 $\mu$ sec Frequency limited by $T_J$ max. $V_A$ =1.5 $\times$ V $_R$ typical	8	А

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#### **Electrical Characteristics:**

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop (Per leg) *	V <sub>F1</sub>	@ 40A, Pulse, T <sub>J</sub> = 25 °C @ 80A, Pulse, T <sub>J</sub> = 25 °C	0.47 0.53	0.51 0.59	V
	V <sub>F2</sub>	@ 40A, Pulse, T <sub>J</sub> = 125 °C @ 80A, Pulse, T <sub>J</sub> = 125 °C	0.38 0.43	0.41 0.51	V
Reverse Current (Per leg) *	I <sub>R1</sub>	@V <sub>R</sub> = rated VR T <sub>J</sub> = 25 °C	0.17	5	mA
	I <sub>R2</sub>	@V <sub>R</sub> = rated VR T <sub>J</sub> = 125 °C	38	280	mA
Junction Capacitance (Per leg)	Ст	$@V_R = 5V, T_C = 25 \text{ °C}$ $f_{SIG} = 1MHz$	2800	3700	pF

<sup>\*</sup> Pulse width < 300 µs, duty cycle < 2%

# **Thermal-Mechanical Specifications:**

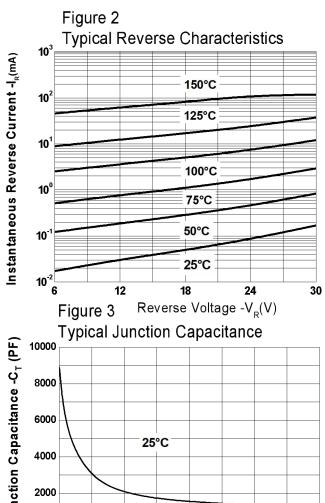
Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T <sub>stg</sub>	-	-55 to +150	°C
Typical Thermal Resistance Junction to Case (per leg)	R <sub>θJC</sub>	DC operation	0.5	°C/W
Typical Thermal Resistance Junction to Case (per package)	$R_{ heta JC}$	DC operation	0.25	°C/W
Typical Thermal Resistance, case to Heat Sink	R <sub>θcs</sub>	Mounting surface, smooth and greased	0.21	°C/W
Mounting Torque	TM		40(min)	Kg-cm
Mounting Torque	I IVI	-	58(max)	Ng-CIII
Case Style	PRM2 PRM2-SL PRM2-SM			



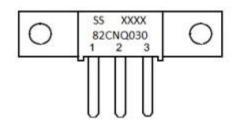


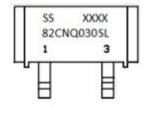


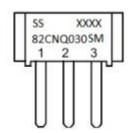
#### **Ratings and Characteristics Curves**



## **Marking Diagram**







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Where XXXX is YYWW

20

Reverse Voltage -V<sub>P</sub>(V)

1st row SS YYWWL
2nd row82CNQ030/SL/SM
3rd row 1 2 3 (pin)
SS = SS
YY = Year

= Week

Cautions: Molding resin

WW

Epoxy resin UL:94V-0

40

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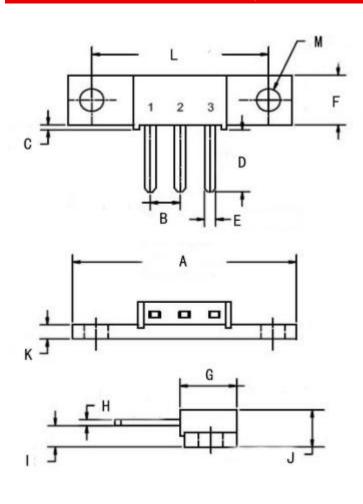




# **Ordering Information**

Device	Package	Approximate Weight(g)	Terminals finish	Baseplate finish	Shipping
82CNQ030	PRM2	8.6	Nickel plated	Nickel plated	48pcs / box
82CNQ030S2	PRM2	8.6	Pure Sn dipped (dipped heigh 6-8mm)	Nickel plated	48pcs / box
82CNQ030SL	PRM2-SL	5.3	Pure Sn plated	Pure Sn plated	100pcs / box
82CNQ030SM	PRM2-SM	5.6	Nickel plated	Nickel plated	48pcs / box
82CNQ030SMS2	PRM2-SM	5.6	Pure Sn dipped (dipped heigh 6-8mm)	Nickel plated	48pcs / box

### **Mechanical Dimensions PRM2 (Inches/Millimeters)**



SYMBOL	MillImeters		Inches		
STINIBOL	Min.	Max.	Min.	Max.	
А	37.72	38.23	1.485	1.506	
В	5.	08	0.200		
С	0.62	1.02	0.024	0.040	
D	10.38	12.98	0.408	0.511	
E	1.78	2.28	0.070	0.090	
F	8.46	9.06	0.333	0.357	
G	9.24	9.85	0.363	0.388	
Н	0.75	1.15	0.029	0.046	
I	3.19	4.19	0.125	0.165	
J	6.95	7.55	0.273	0.298	
К	2.40	2.60	0.094	0.103	
L	29.51	30.40	1.161	1.197	
М	3.75	4.33	0.147	0.171	

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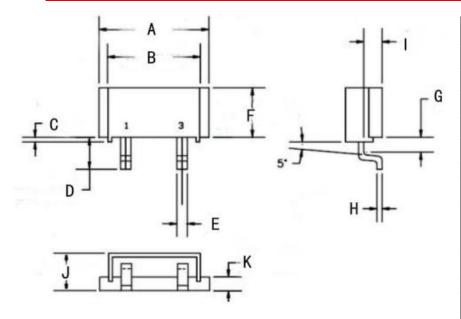
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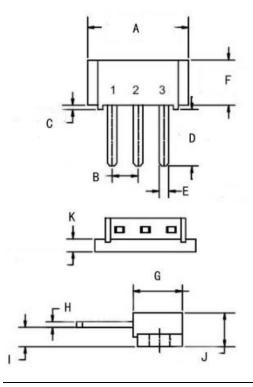


## **Mechanical Dimensions PRM2-SL (Inches/Millimeters)**



SYMBOL	MillImeters		Inches	
OTWIDOL	Min.	Max.	Min.	Max.
А	19.70	20.30	0.776	0.799
В	16.51	17.02	0.650	0.670
С	0.62	1.02	0.024	0.040
D	4.97	5.97	0.196	0.235
E	1.78	2.28	0.070	0.090
F	8.46	9.06	0.333	0.357
G	2.04	2.54	0.080	0.100
Н	0.75	1.15	0.029	0.045
I	3.19	4.19	0.125	0.165
J	6.95	7.55	0.274	0.297
K	2.21	2.71	0.087	0.106
А	19.70	20.30	0.776	0.799

## **Mechanical Dimensions PRM2-SM (Inches/Millimeters)**



SYMBOL	MillImeters		Inches		
	Min.	Max.	Min.	Max.	
А	19.70	20.30	0.776	0.799	
В	5.08		0.200		
С	0.62	1.02	0.024	0.040	
D	10.38	12.98	0.408	0.511	
Е	1.78	2.28	0.070	0.090	
F	8.46	9.06	0.333	0.357	
G	9.24	9.85	0.363	0.388	
Н	0.75	1.15	0.029	0.045	
I	3.19	4.19	0.125	0.165	
J	6.95	7.55	0.273	0.298	
K	2.21	2.71	0.087	0.106	

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